

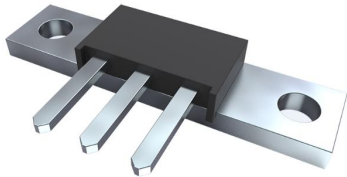

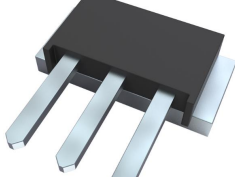
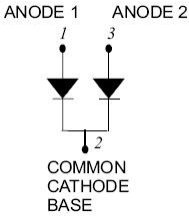
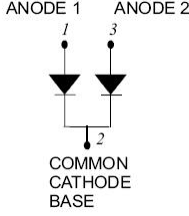
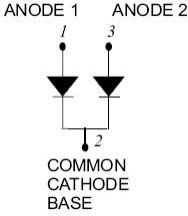
113CNQ100 SCHOTTKY RECTIFIER

Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Features

- 175°C T_J operation
- Center tap module
- Very Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Low profile, high current package
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional electrical and life testing can be performed upon request

113CNQ100	113CNQ100SL	113CNQ100SM
		
 <p>ANODE 1 ANODE 2 COMMON CATHODE BASE</p>	 <p>ANODE 1 ANODE 2 COMMON CATHODE BASE</p>	 <p>ANODE 1 ANODE 2 COMMON CATHODE BASE</p>
PRM2	PRM2-SL	PRM2-SM

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	100	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @T _C =95°C, rectangular wave form	55(Per Leg) 110(Per Device)	A
Peak One Cycle Non-Repetitive Surge Current (per leg)	I _{FSM}	10 ms, half Sine pulse	720	A
Non-Repetitive Avalanche Energy(peg leg)	E _{AS}	T _J =25°C, I _{AS} =1A, L=30mH	15	mJ
Repetitive Avalanche Current(peg leg)	I _{AR}	Current decaying linearly to zero in 1 μsec Frequency limited by T _J max. V _A =1.5×V _R typical	1	A

Electrical Characteristics:

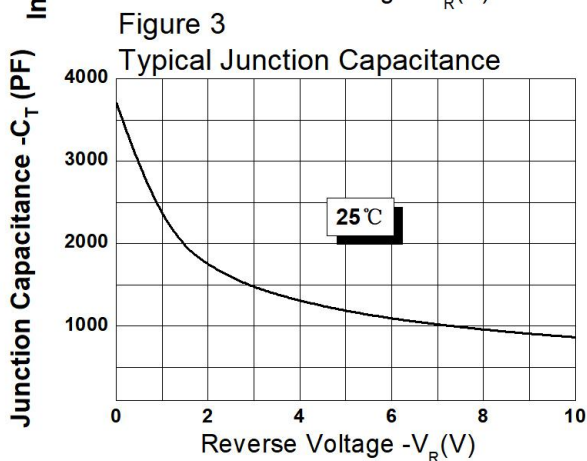
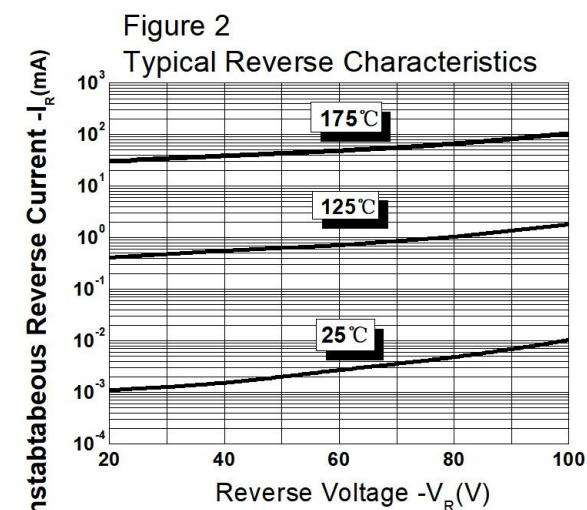
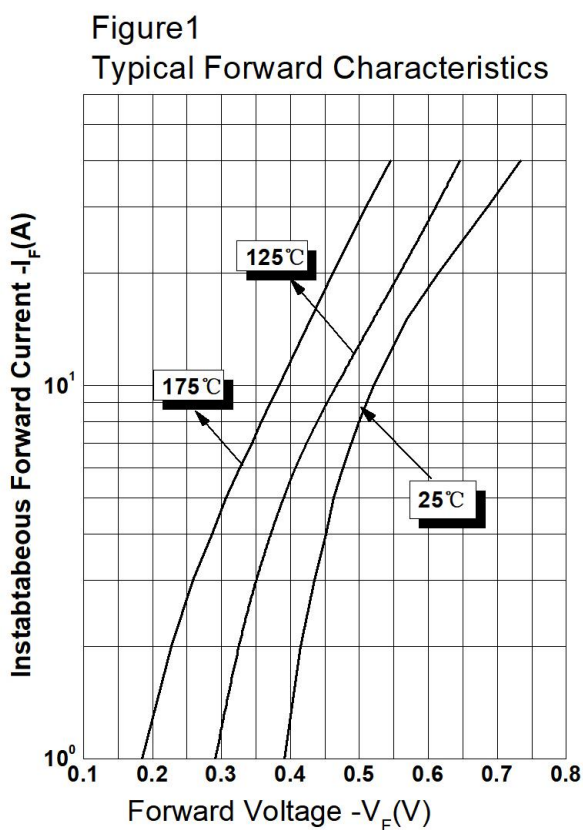
Characteristics	Symbol	Condition	Typ.	Max.	Units
Forward Voltage Drop (Per leg) *	V _{F1}	@ 55A, Pulse, T _J = 25 °C @110A, Pulse, T _J = 25 °C	- -	0.81 1.00	V
	V _{F2}	@ 55A, Pulse, T _J = 125 °C @ 110A, Pulse, T _J = 125 °C	- -	0.66 0.79	V
Reverse Current (Per leg) *	I _{R1}	@V _R = rated VR T _J = 25 °C	0.01	1	mA
	I _{R2}	@V _R = rated VR T _J = 125 °C	1.8	32	mA
Junction Capacitance (Per leg)	C _T	@V _R = 5V, T _C = 25 °C f _{sig} = 1MHz	1180	1960	pF

* Pulse width < 300 μs, duty cycle < 2%

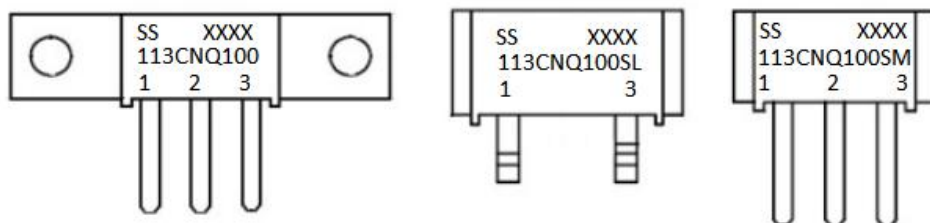
Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	T _J	-	-55 to +175	°C
Storage Temperature	T _{stg}	-	-55 to +175	°C
Typical Thermal Resistance Junction to Case (per leg)	R _{θJC}	DC operation	0.50	°C/W
Typical Thermal Resistance Junction to Case (per package)	R _{θJC}	DC operation	0.25	°C/W
Typical Thermal Resistance, case to Heat Sink	R _{θcs}	Mounting surface, smooth and greased	0.30	°C/W
Mounting Torque	TM	-	40(min)	Kg-cm
			58(max)	
Approximate Weight	wt	-	7.8	g
Case Style	PRM2 PRM2-SL PRM2-SM			

Ratings and Characteristics Curves



Marking Diagram



Where XXXX is YYWW

1st row SS YYWWL
2nd row 113CNQ100/SL/SM
3rd row 1 2 3 (pin)
SS = SS
YY = Year
WW = Week

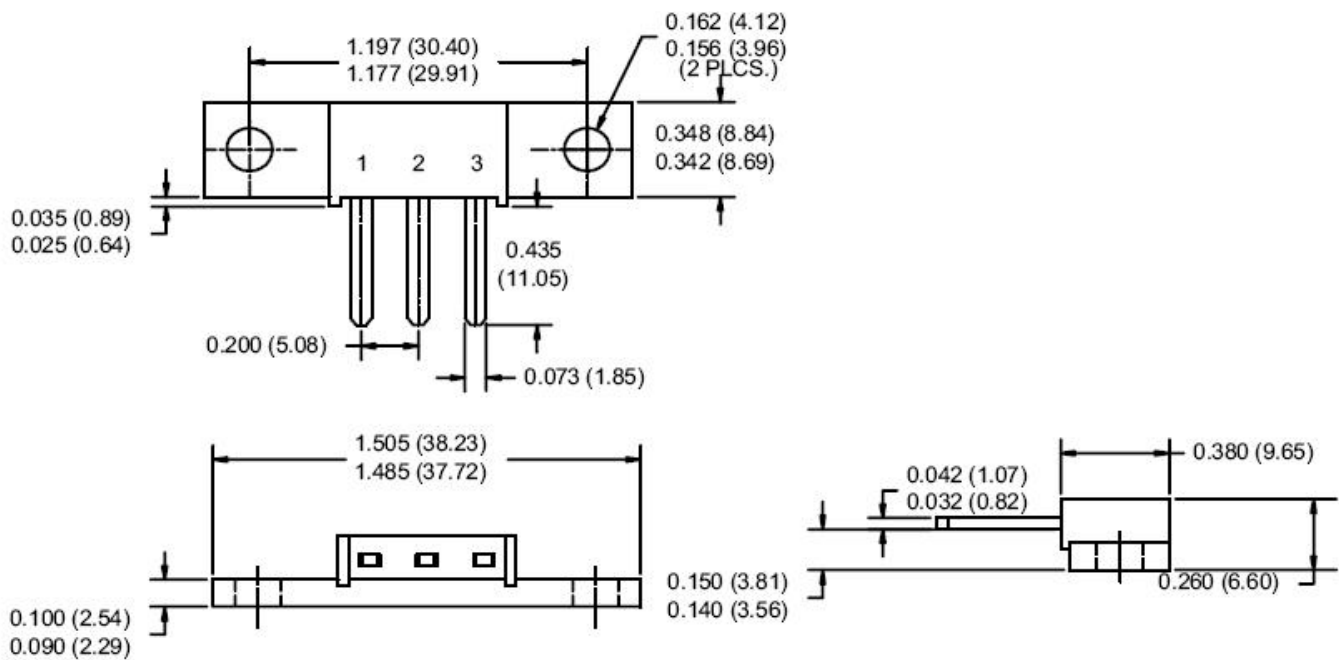
Cautions: Molding resin
Epoxy resin UL:94V-0

Ordering Information

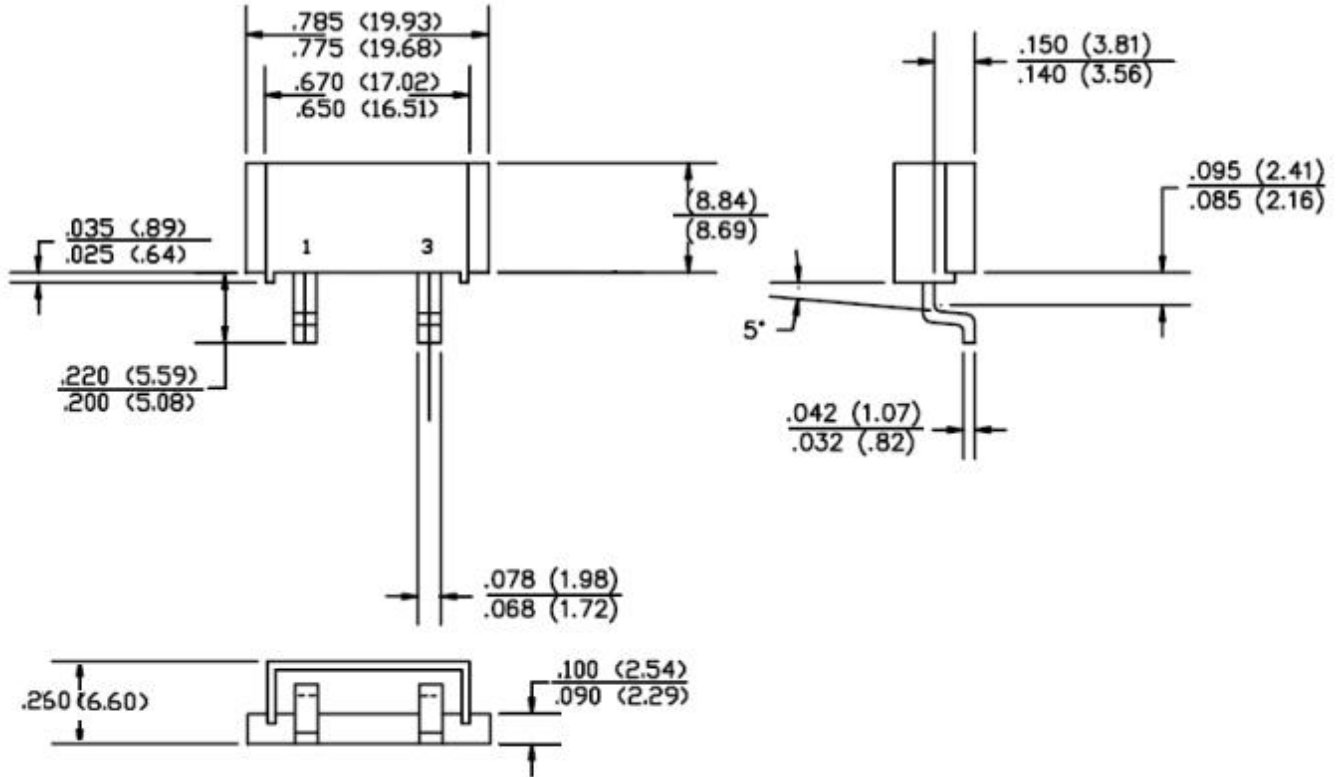
Device	Package	Terminals finish	Baseplate finish	Shipping
113CNQ100	PRM2	Nickel plated	Nickel plated	48pcs / box
113CNQ100S2	PRM2	Pure Sn dipped (dipped heigh 6-8mm)	Nickel plated	48pcs / box
113CNQ100SL	PRM2-SL	Pure Sn plated	Pure Sn plated	100pcs / box
113CNQ100SM	PRM2-SM	Nickel plated	Nickel plated	48pcs / box
113CNQ100SMS2	PRM2-SM	Pure Sn dipped (dipped heigh 6-8mm)	Nickel plated	48pcs / box

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

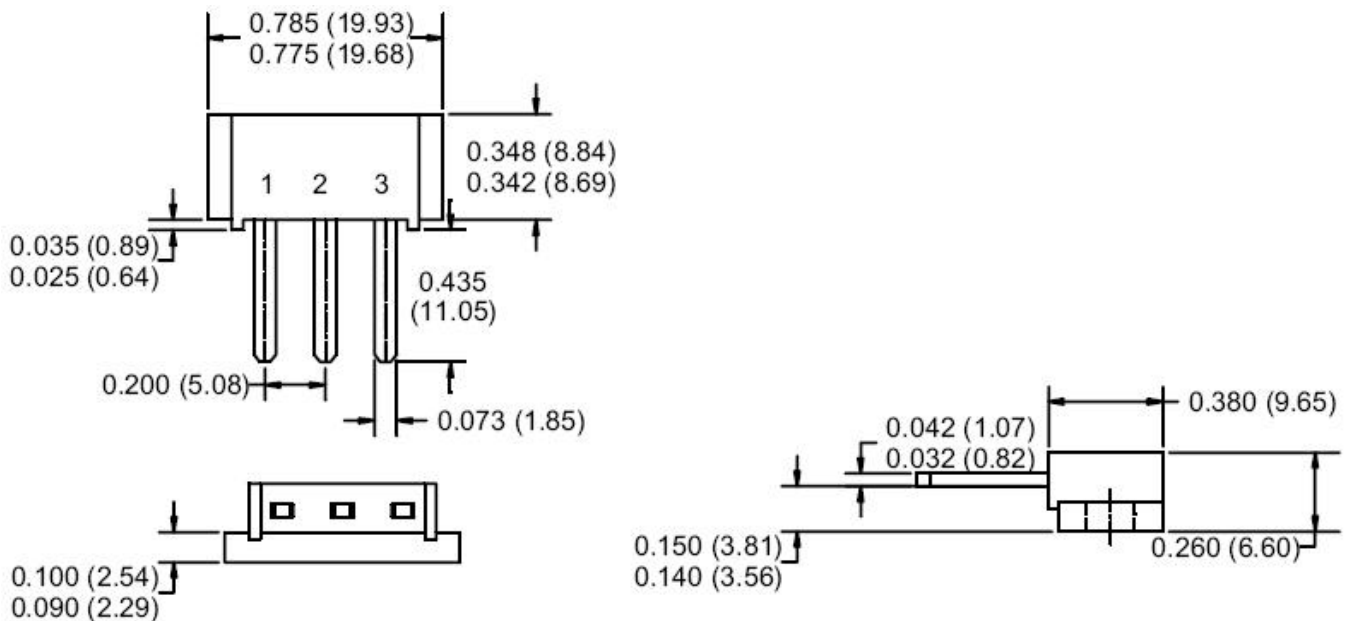
Mechanical Dimensions PRM2 (Inches/Millimeters)



Mechanical Dimensions PRM2-SL (Inches/Millimeters)



Mechanical Dimensions PRM2-SM (Inches/Millimeters)



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